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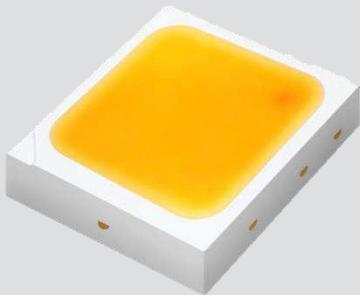
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## Middle Power LED Series 3030

# LM301A CRI 70



### Features & Benefits

- Superior mid power LED with wide over-drive range up to 1.5W
- Mold resin for high reliability
- Standard form factor for design flexibility (3.0 × 3.0 mm)



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## 1. Characteristics

### a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	T <sub>a</sub>	-40 ~ +85	°C	-
Storage Temperature	T <sub>stg</sub>	-40 ~ +100	°C	-
LED Junction Temperature	T <sub>j</sub>	125	°C	-
Forward Current	I <sub>F</sub>	500	mA	-
Assembly Process Temperature	-	260 <10	°C s	-
ESD (HBM)	-	5	kV	-



**b) Electro-optical Characteristics ( $I_F = 150 \text{ mA}$ ,  $T_s = 85^\circ\text{C}$ )**

Item	Unit	Rank	Bin	Min.	Typ.	Max.
Forward Voltage ( $V_F$ )	V	WA	AY	2.6	-	2.7
			AZ	2.7	-	2.8
			A1	2.8	-	2.9
			A2	2.9	-	3.0
			A3	3.0	-	3.1
				0.7	-	1.2
Reverse Voltage (@ 5 mA)	V			70	-	-
Color Rendering Index ( $R_e$ )	-			-	-	-
Special CRI (R9)	-			-	-	-
Thermal Resistance (junction to solder point)	°C/W			-	7	-
Beam Angle	°			-	115	-

**Note:**

Samsung maintains measurement tolerance of: forward voltage =  $\pm 0.1 \text{ V}$ , CRI =  $\pm 3$ , R9 =  $\pm 6.5$



**b) Electro-optical Characteristics ( $T_s = 85^\circ\text{C}$ )**

Item	CRI	Nominal CCT (K)	SD		SE		SF		SG		SH		Current
			Min.	Max.									
			24	26	26	28	28	30	30	32	32	34	65mA
			54	58	58	62	62	66	66	70	70	74	150mA
Luminous Flux ( $\Phi_v$ )	70	3000											
		3500											
		4000											
		5000											

**Note:**

Samsung maintains measurement tolerance of: forward voltage =  $\pm 0.1\text{V}$ , luminous flux =  $\pm 5\%$ , CRI =  $\pm 3$ , R9 =  $\pm 6.5$

Calculated luminous flux values at 65mA and 350mA are for reference only.



## 2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	P	M	W	H	T	3	2	8	F	D	3	W	A	R	0	S	0

Digit	PKG Information		Code	Specification	
1 2 3	Samsung Package Middle Power		SPM		
4 5	Color		WH	White	
6	Product Version		T		
7 8 9	Form Factor		328	3.0 x 3.0 x 0.65 mm; 2 pads; 1chip;	
10	Sorting Current (mA)		F	150 mA	
11	Chromaticity Coordinates		D	ANSI Standard	
12	CRI		3	Min. 70	
13 14	Forward Voltage (V)		WA	2.6~3.1V	
15 16	CCT (K)		V★ U★ T★ R★	3000 V1, V2, V3, V4, V5, V6, V7, V8, V9, VA, VB, VC, VD, VE, VF, VG 3500 U1, U2, U3, U4, U5, U6, U7, U8, U9, UA, UB, UC, UD, UE, UF, UG 4000 T1, T2, T3, T4, T5, T6, T7, T8, T9, TA, TB, TC, TD, TE, TF, TG 5000 R1, R2, R3, R4, R5, R6, R7, R8, R9, RA, RB, RC, RD, RE, RF, RG	
	Bin Code: ★ : Cool white: "0" (Whole bin) or "K" (Kitting bin)				
17 18	Luminous Flux		S0	Bin Code: SE, SF, SG	



a) Luminous Flux Bins ( $I_F = 150 \text{ mA}$ ,  $T_s = 85^\circ\text{C}$ )

CRI ( $R_a$ ) Min.	Nominal CCT (K)	Product Code	Flux Bin	Flux Range ( $\Phi_v$ , lm)
3000	SPMWHT328FD3WAV★S0		SE	58 ~ 62
			SF	62 ~ 66
3500	SPMWHT328FD3WAU★S0		SE	58 ~ 62
			SF	62 ~ 66
70				
4000	SPMWHT328FD3WAT★S0		SF	62 ~ 66
			SG	66 ~ 70
5000	SPMWHT328FD3WAR★S0		SF	62 ~ 66
			SG	66 ~ 70

**Note:**

"★" can be "0" (Whole bin) or "K" (Kitting bin) of the color binning

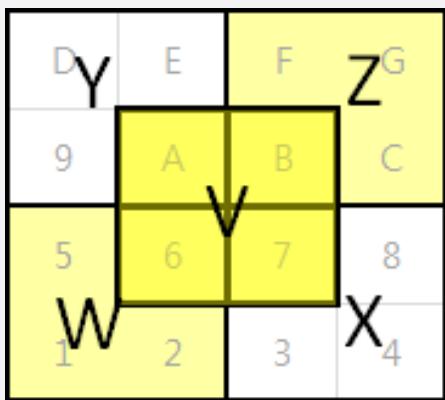


## b) Kitting rule

### 1) Kitting bin Concept

- Under agreement between customer and SAMSUNG ELECTRONICS, SAMSUNG can supply kitting bin (VF, Color, Im).
- A forward voltage (VF) of kitting bin is combined by a pair of same VF rank such as (AY+AY), (AZ+AZ), (A1+A1), (A2+A2) or (A3+A3).
- A Chromaticity Coordinates of kitting bin is mixed by kitting procedure.(below kitting simulation)

### [Kitting example]



### [Binning Information]

Item	Bin #1	Bin #2
VF	AY	AY
	AZ	AZ
	A1	A1
	A2	A2
	A3	A3
CIE	W (1, 2, 5, 6 bin)	Z (B, C, F, G bin)
	V (6, 7, A, B bin)	V (6, 7, A, B bin)
	X (3, 4, 7, 8 bin)	Y (9, A, D, E bin )
IV	SE	SE
	SF	SF
	SG	SG

※ Each of V,W,X,Y and Z can be one bin without details division.

c) Color Bins ( $I_F = 150 \text{ mA}$ ,  $T_s = 85^\circ\text{C}$ )

CRI ( $R_a$ ) Min.	Nominal CCT (K)	Product Code	Color Rank	Chromaticity Bins
70	3000	SPMWHT328FD3WAV0S0	V0 (Whole bin)	V1, V2, V3, V4, V5, V6, V7, V8, V9, VA, VB, VC, VD, VE, VF, VG
		SPMWHT328FD3WAVKS0	VK (Kitting bin)	VV, VW, VX, VY, VZ
	3500	SPMWHT328FD3WAU0S0	U0 (Whole bin)	U1, U2, U3, U4, U5, U6, U7, U8, U9, UA, UB, UC, UD, UE, UF,UG
		SPMWHT328FD3WAUKS0	UK (Kitting bin)	UV, UW, UX, UY, UZ
	4000	SPMWHT328FD3WAT0S0	T0 (Whole bin)	T1, T2, T3, T4, T5, T6, T7, T8, T9, TA, TB, TC, TD, TE, TF, TG
		SPMWHT328FD3WATKS0	TK (Kitting bin)	TV, TW, TX, TY, TZ
	5000	SPMWHT328FD3WAR0S0	R0 (Whole bin)	R1, R2, R3, R4, R5, R6, R7, R8, R9 RA, RB, RC, RD, RE, RF, RG
		SPMWHT328FD3WARKS0	RK (Kitting bin)	RV, RW, RX, RY, RZ

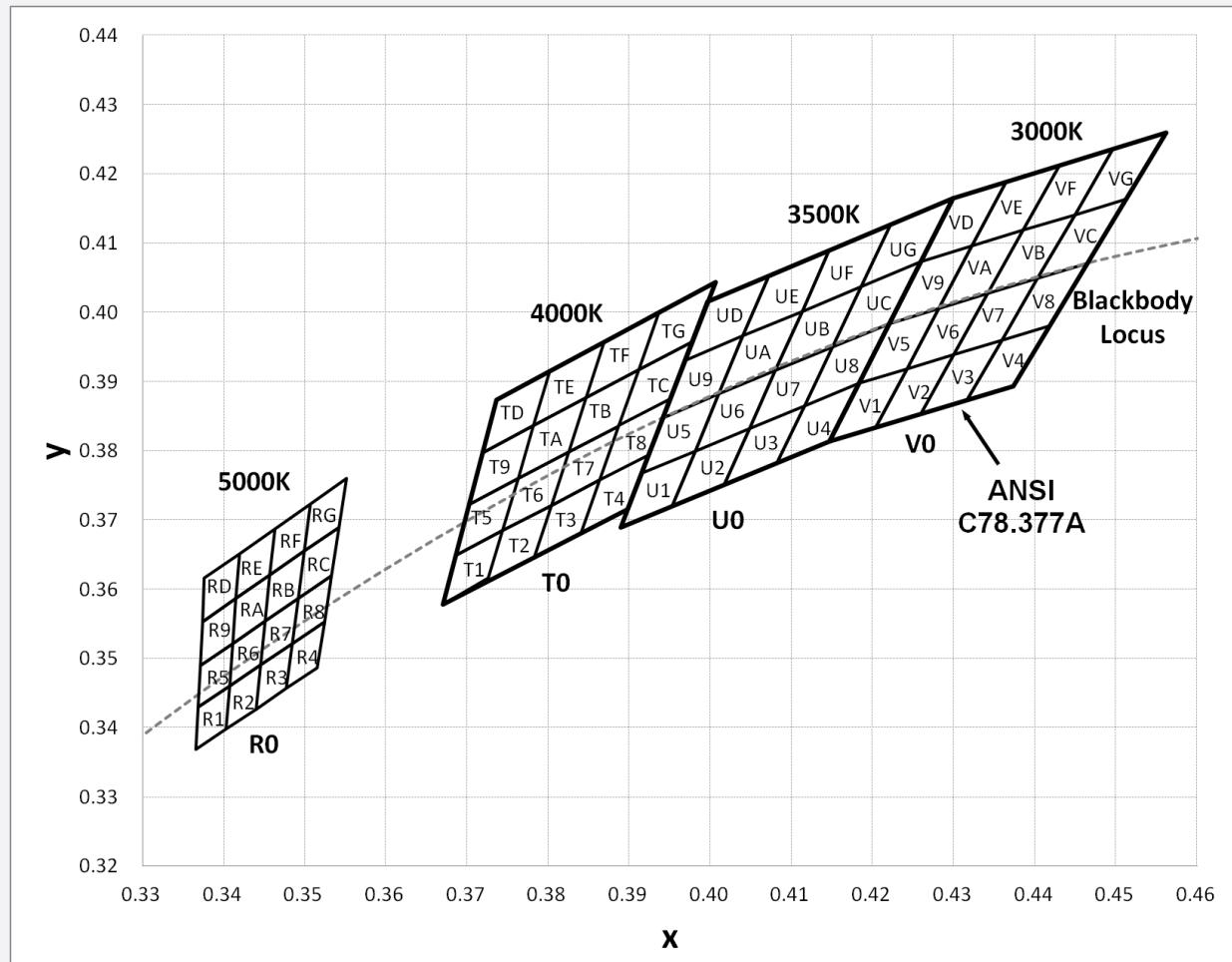


d) Voltage Bins ( $I_F = 150 \text{ mA}$ ,  $T_s = 85^\circ\text{C}$ )

CRI ( $R_a$ ) Min.	Nominal CCT (K)	Product Code	Voltage Rank	Voltage Bin	Voltage Range (V)
-	-	-	AY	A1	2.6 ~ 2.7
-	-	-	AZ	A2	2.7 ~ 2.8
-	-	-	WA	A3	2.8 ~ 2.9
-	-	-	-	A2	2.9 ~ 3.0
-	-	-	-	A3	3.0 ~ 3.1



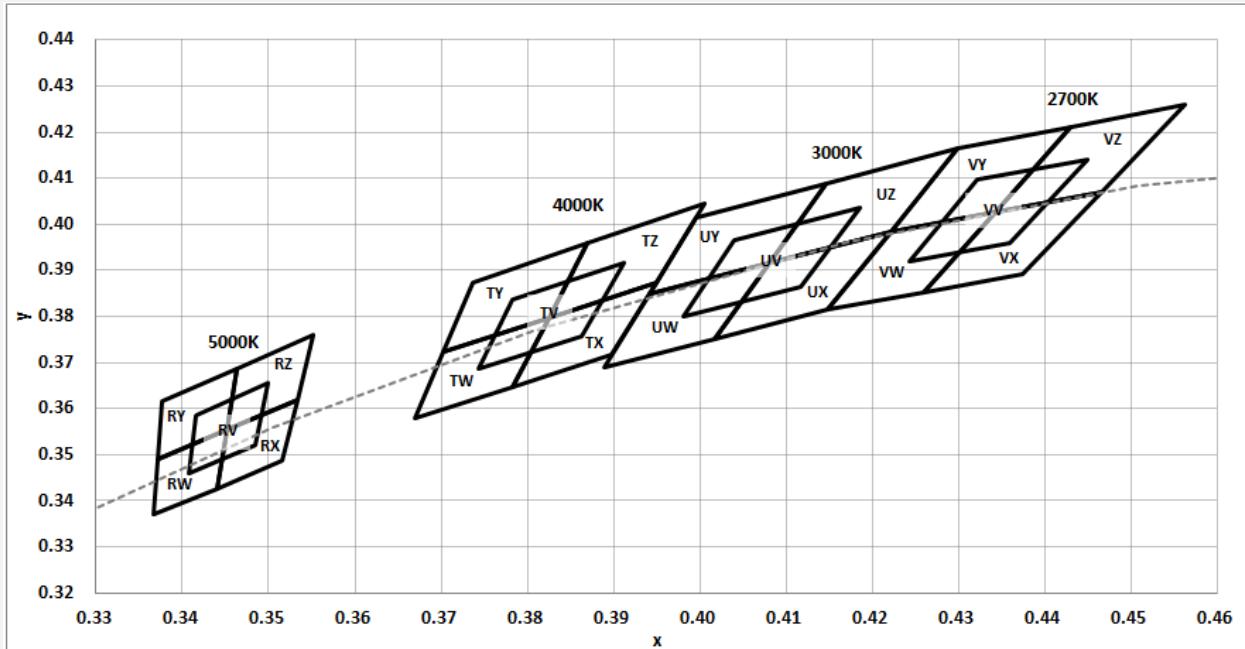
e) Chromaticity Region & Coordinates ( $I_F = 150 \text{ mA}$ ,  $T_s = 85^\circ\text{C}$ )







f) Kitting Chromaticity Region & Coordinates ( $I_F = 150 \text{ mA}$ ,  $T_s = 85^\circ\text{C}$ )



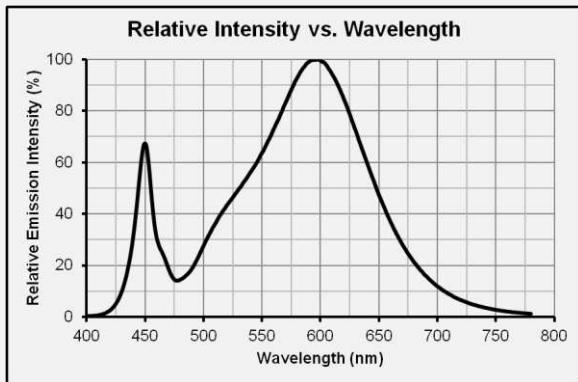
Note: Samsung maintains measurement tolerance of:  $C_x, C_y = \pm 0.005$



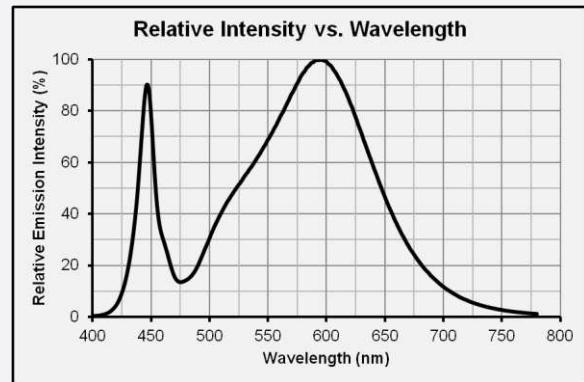
### 3. Typical Characteristics Graphs

#### a) Spectrum Distribution ( $I_F = 150 \text{ mA}$ , $T_s = 85^\circ\text{C}$ )

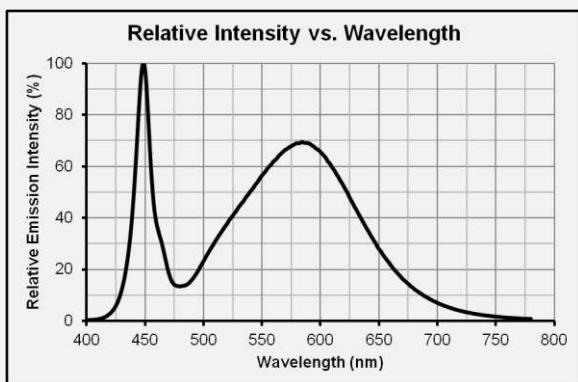
CCT: 3000K (70 CRI)



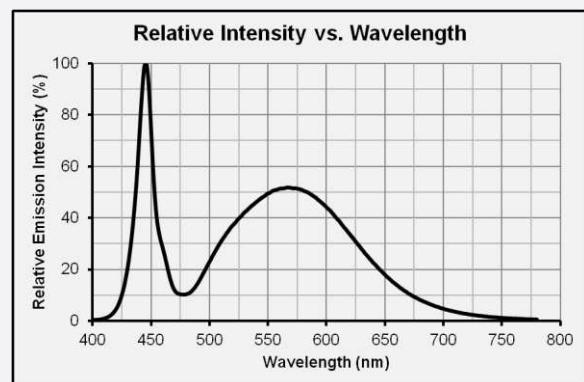
CCT: 3500K (70 CRI)



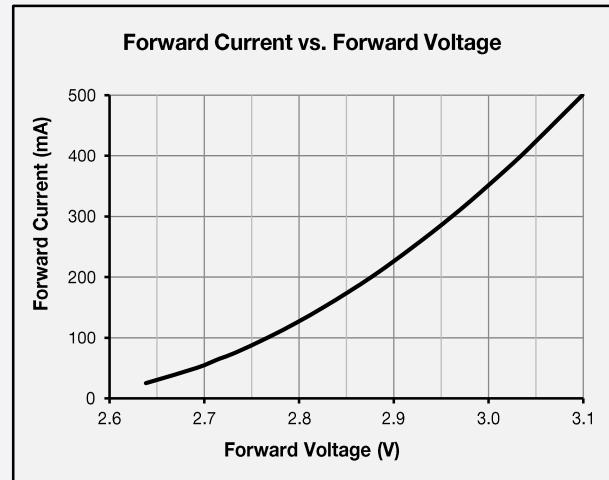
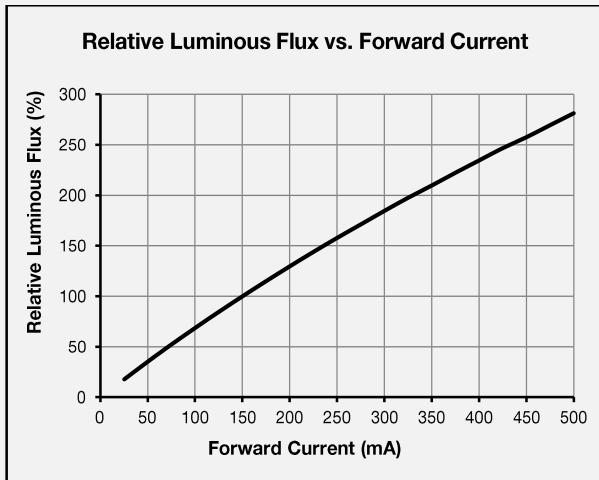
CCT: 4000K (70 CRI)



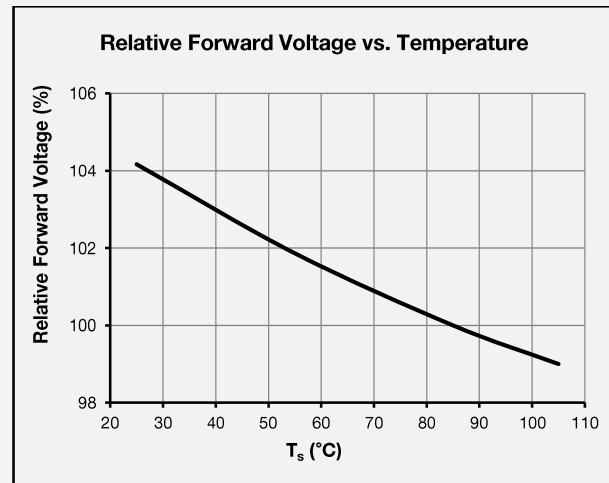
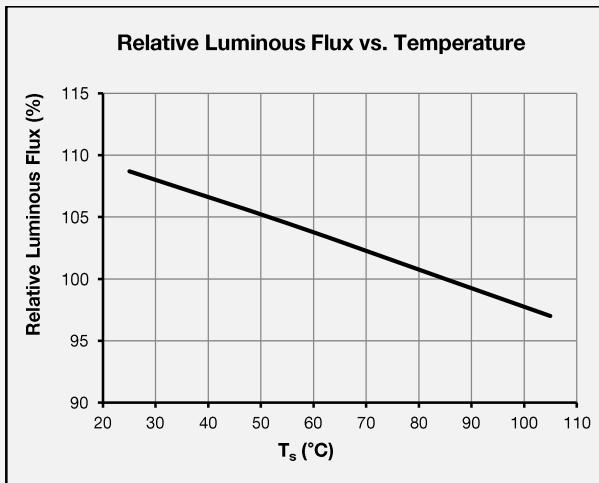
CCT: 5000K (70 CRI)



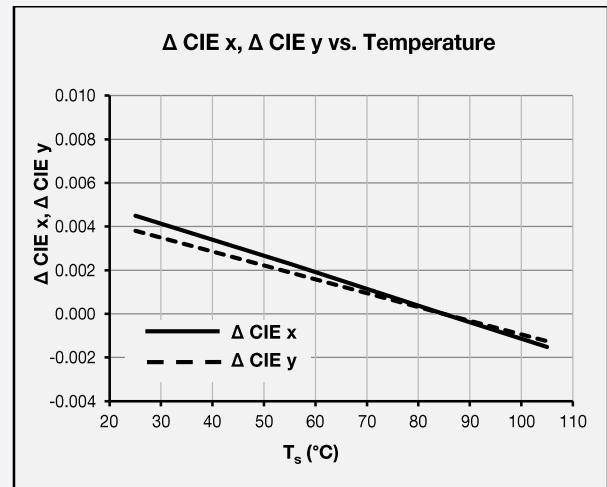
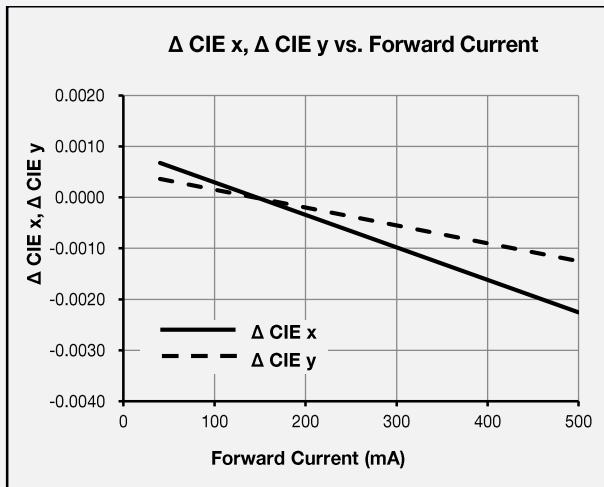
b) Forward Current Characteristics ( $T_s = 85^\circ\text{C}$ )



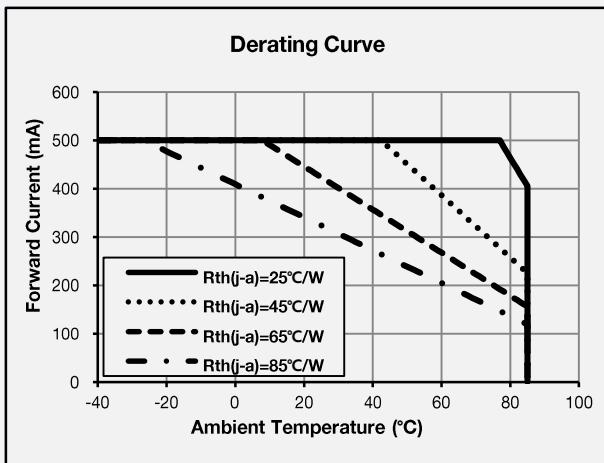
c) Temperature Characteristics ( $I_F = 150 \text{ mA}$ )



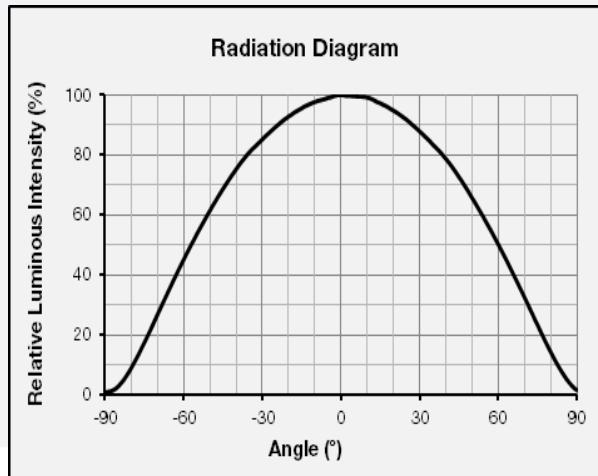
d) Color Shift Characteristics ( $I_F = 150 \text{ mA}$ ,  $T_s = 85^\circ\text{C}$ )



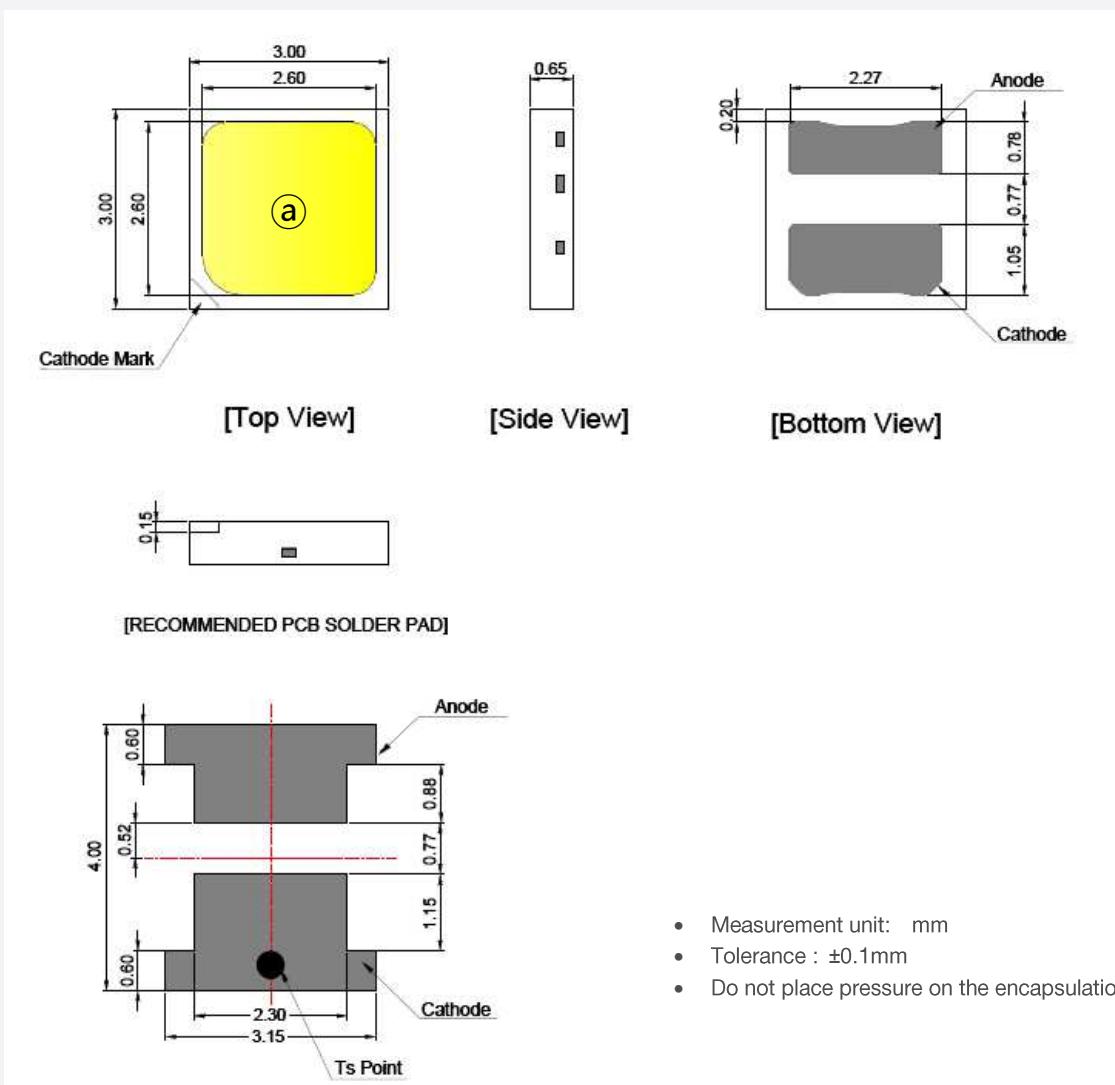
e) Derating Curve



f) Beam Angle Characteristics ( $I_F = 150 \text{ mA}$ ,  $T_s = 85^\circ\text{C}$ )



#### 4. Outline Drawing & Dimension



#### Notes:

- 1) This LED has built-in ESD protection device(s) connected in parallel to LED chip(s).
- 2)  $T_s$  point and measurement method:
  - ① Measure one point at the cathode pad, if necessary remove PSR of PCB to reach  $T_s$  point.
  - ② All pads must be soldered to the PCB to dissipate heat properly, otherwise the LED can be damaged.

#### Precautions:

- 1) Pressure on the LEDs will influence to the reliability of the LEDs. Precautions should be taken to avoid strong pressure on the LEDs. Do not put stress on the LEDs during heating.
- 2) Re-soldering should not be done after the LEDs have been soldered. If re-soldering is unavoidable, LED's characteristics should be carefully checked before and after such repair.
- 3) Do not stack assembled PCBs together. Since materials of LEDs is soft, abrasion between two PCB assembled with LED might cause catastrophic failure of the LEDs.

## 5. Reliability Test Items & Conditions

### a) Test Items

Test Item	Test Condition	Test Hour / Cycle	Sample No.
Room Temperature Life Test	25 °C, DC 500 mA	1000 h	22
High Temperature Life Test	85 °C, DC 500 mA	1000 h	22
High Temperature Humidity Life Test	85 °C, 85 % RH, DC 500 mA	1000 h	22
Low Temperature Life Test	-40 °C, DC 500 mA	1000 h	22
Powered Temperature Cycle Test	-45 °C ~ 85 °C, each 10 min, on/off 5 min Temp. Change time 20min, DC 500 mA	100 cycles	22
Temperature Cycling	-45 °C / 15 min ↔ 125 °C / 15 min → Hot plate 180°C	500 cycles	100
High Temperature Storage	120 °C	1000 h	11
Low Temperature Storage	-40 °C	1000 h	11
ESD (HBM)		R <sub>1</sub> : 10 MΩ R <sub>2</sub> : 1.5 kΩ 5 times	30
ESD (MM)		R <sub>1</sub> : 10 MΩ R <sub>2</sub> : 0 C: 200 pF V: ±0.5 kV	5 times
Vibration Test	20~2000~20 Hz, 200 m/s <sup>2</sup> , sweep 4 min X, Y, Z 3 direction, each 1 cycle	4 cycles	11
Mechanical Shock Test	1500 g, 0.5 ms 3 shocks each X-Y-Z axis	5 cycles	11

### b) Criteria for Judging the Damage

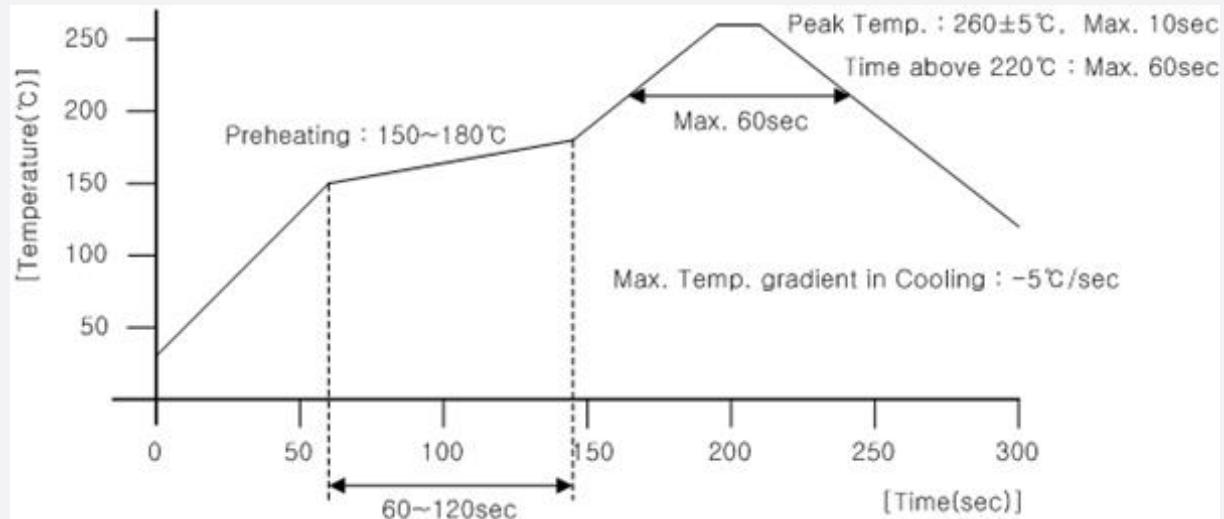
Item	Symbol	Test Condition (T <sub>s</sub> = 25 °C)	Limit	
			Min	Max
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 500 mA	Init. Value * 0.9	Init. Value * 1.1
Luminous Flux	Φ <sub>v</sub>	I <sub>F</sub> = 500 mA	Init. Value * 0.7	Init. Value * 1.1



## 6. Soldering Conditions

### a) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.



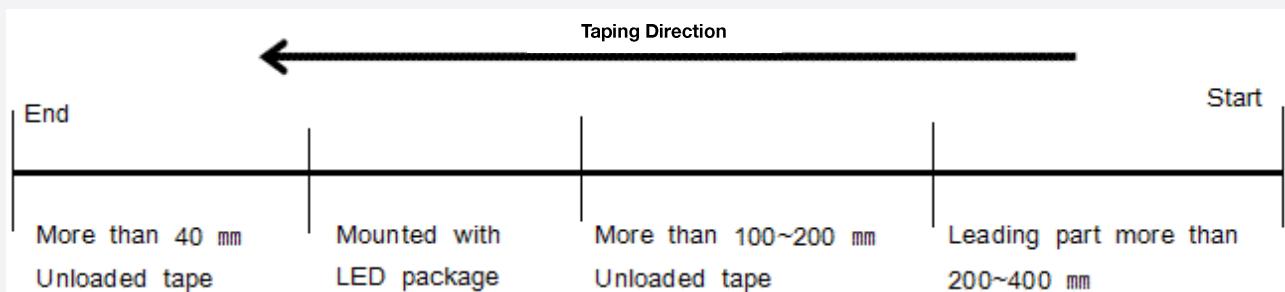
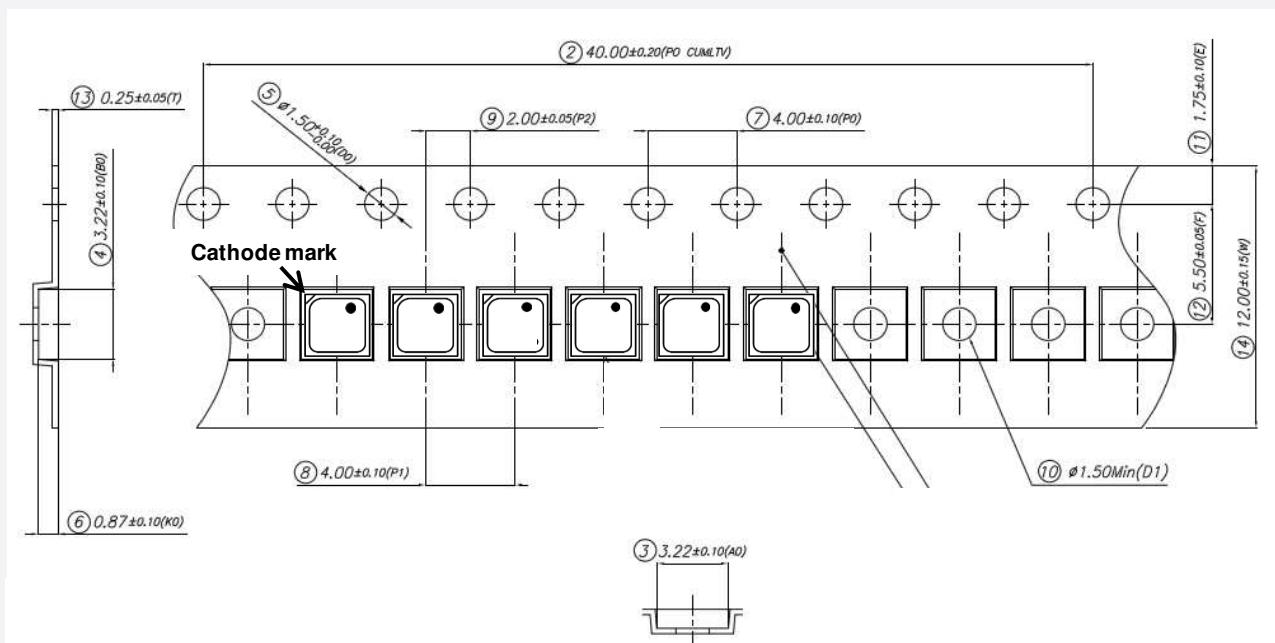
### b) Manual Soldering Conditions

Not more than 5 seconds @ max. 300 °C, under soldering iron.

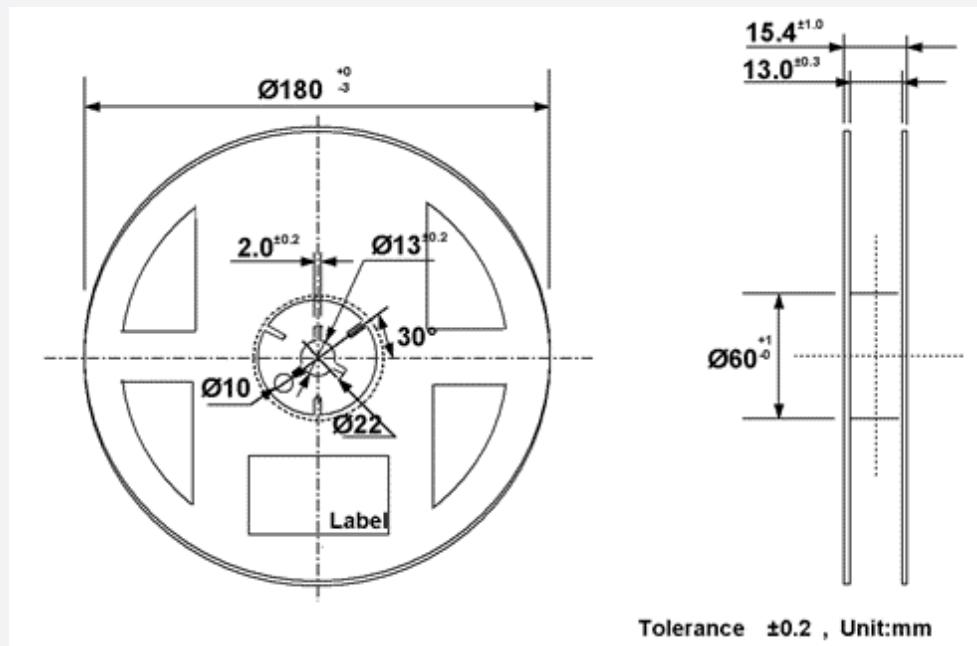
## 7. Tape & Reel

### a) Taping Dimension

(unit: mm)



### b) Reel Dimension

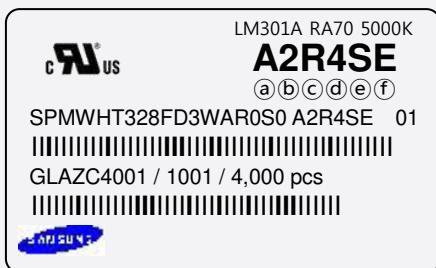


#### Notes:

- 1) Quantity: The quantity/reel is 4,000 pcs
- 2) Cumulative tolerance: Cumulative tolerance / 10 pitches is  $\pm 0.2$  mm
- 3) Adhesion strength of cover tape: Adhesion strength is 0.1-0.7 N when the cover tape is turned off from the carrier tape at  $10^\circ$  angle to the carrier tape
- 4) Packaging: P/N, Manufacturing data code no. and quantity are indicated on the aluminum packing bag

## 8. Label Structure

### a) Label Structure



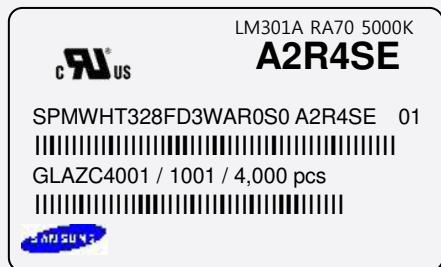
Note: Denoted bin code and product code above is only an example

'★' means all kind of Chromaticity Coordinate Ranks

Bin Code:

- ⒶⒷ: Forward Voltage bin (refer to page 9)
- ⒸⒹ: Chromaticity bin (refer to page 11~14)
- ⒺⒻ: Luminous Flux bin (refer to page 7)

### b) Lot Number



The lot number is composed of the following characters:

①②③④⑤⑥⑦⑧⑨ / 1ⒶⒷⒸ / 4,000 pcs

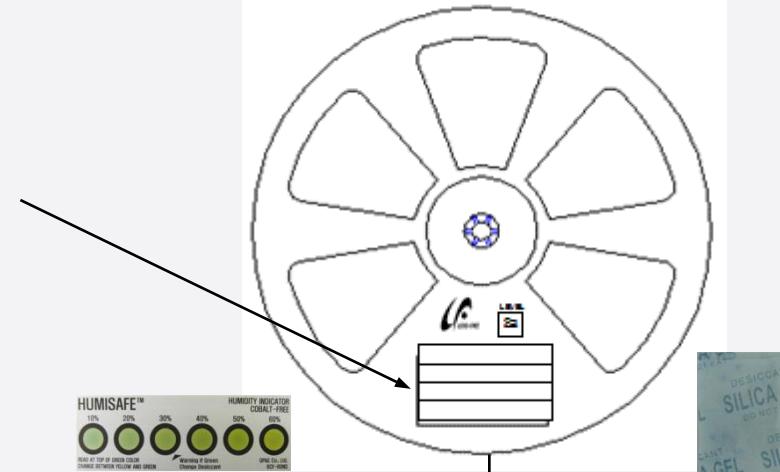
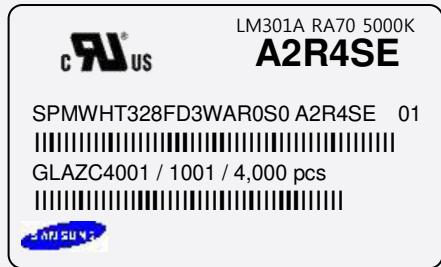
- |     |   |
|-----|---|
| ①   | : Production site (S: Giheung, Korea, G: Tianjin, China)                              |
| ②   | : L (LED)   |
| ③   | : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample) |
| ④   | : Year (Z: 2015, A: 2016, B: 2017 ...)  |
| ⑤   | : Month (1~9, A, B, C)  |
| ⑥   | : Day (1~9, A, B~V)   |
| ⑦⑧⑨ | : Product serial number (001 ~ 999)   |
| ⒶⒷⒸ | : Reel number (001 ~ 999)   |



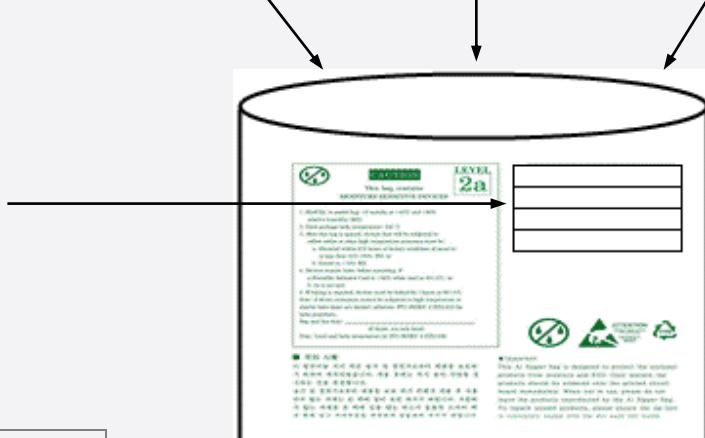
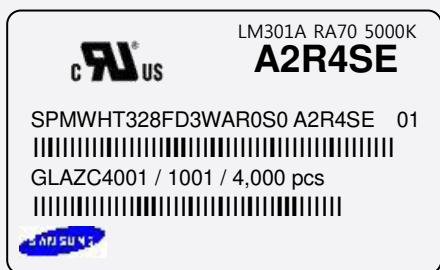
## 9. Packing Structure

### a) Packing Process

Reel



Aluminum Vinyl Packing Bag



Outer Box

Material: Paper (SW3B(B))

Type	Size (mm)			Note
	L	W	H	
7 inch L	245 ± 5	220 ± 5	182 ± 5	Up to 10 reels
7 inch S	245 ± 5	220 ± 5	86 ± 5	Up to 5 reels

① Side Label

